## P-Channel Enhancement-Mode Vertical DMOS FET

## Features

- Free from secondary breakdown
- Low power drive requirement
- Ease of paralleling
- Low $\mathrm{C}_{\text {iss }}$ and fast switching speeds
- High input impedance and high gain
- Excellent thermal stability
- Integral source-to-drain diode


## Applications

- Motor controls
- Converters
- Amplifiers
- Switches
- Power supply circuits
- Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)


## General Description

The Supertex VP2206 is an enhancement-mode (normallyoff) transistor that utilizes a vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors, and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

## Ordering Information

| Device | Package Options |  | Wafer / Die Options |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | TO-39 | TO-92 | NW <br> (Die in wafer form) | NJ <br> (Die on adhesive tape) | ND <br> (Die in waffile pack) |
| VP2206 | VP2206N2 | VP2206N3-G | VP5206NW | VP5206NJ | VP5206ND |

For packaged products, -G indicates package is RoHS compliant ('Green'). TO-39 package is RoHS compliant ('Green').
Devices in Wafer / Die form are RoHS compliant ('Green').
Refer to Die Specification VF52 for layout and dimensions.

## Product Summary

| Device | $\mathrm{BV}_{\mathrm{DSS}} / \mathrm{BV}_{\mathrm{DGS}}$ <br> (V) | $\mathbf{R}_{\mathrm{DS}(\mathrm{ON})}$ (max) (Q) | $I_{D(0 N)}$ <br> (min) <br> (A) |
| :---: | :---: | :---: | :---: |
| VP2206N2 | -60 | 0.9 | -4.0 |
| VP2206N3-G |  |  |  |

## Absolute Maximum Ratings

| Parameter | Value |
| :--- | ---: |
| Drain-to-source voltage | $\mathrm{BV}_{\text {DSS }}$ |
| Drain-to-gate voltage | $\mathrm{BV}_{\text {DGS }}$ |
| Gate-to-source voltage | $\pm 20 \mathrm{~V}$ |
| Operating and storage temperature | $-55^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

[^0]
## Pin Configurations



TO-39 (N2)
Product Marking


Package may or may not include the following marks: Si or $\$ 7$
TO-39 (N2)

$Y Y=$ Year Sealed WW $=$ Week Sealed
$\qquad$

## Thermal Characteristics

| Package | I (continuous) $^{\boldsymbol{t}}$ <br> (A) | $\underset{\text { (pulsed) }}{\mathrm{I}_{\mathrm{D}}}$ <br> (A) | Power Dissipation <br> @ $\mathrm{T}_{\mathrm{c}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ <br> (W) | $\begin{gathered} \boldsymbol{\theta}_{J C} \\ \left({ }^{\circ} \mathrm{C} / \mathrm{W}\right) \end{gathered}$ | $\begin{gathered} \boldsymbol{\theta}_{J A} \\ \left({ }^{\circ} \mathrm{C} / \mathrm{W}\right) \end{gathered}$ | $\mathrm{I}_{\mathrm{DR}}{ }^{\dagger}$ <br> (A) | $I_{\text {DRM }}$ <br> (A) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TO-39 | -0.75 | -8.0 | 6.0 | 20.8 | 125 | -0.75 | -8.0 |
| TO-92 | -0.64 | -4.0 | 1.0 | 125 | 170 | -0.64 | -4.0 |

## Notes:

$\dagger \quad I_{D}$ (continuous) is limited by max rated $T_{J}$
Electrical Characteristics $\left(T_{A}=25^{\circ} \mathrm{C}\right.$ unless othemise specified $)$

| Sym | Parameter | Min | Typ | Max | Units | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BV ${ }_{\text {DSs }}$ | Drain-to-source breakdown voltage | -60 | - | - | V | $V_{G S}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-10 \mathrm{~mA}$ |
| $\mathrm{V}_{\text {GS(th) }}$ | Gate threshold voltage | -1.0 | - | -3.5 | V | $V_{G S}=V_{D S}, I_{D}=-10 \mathrm{~mA}$ |
| $\Delta \mathrm{V}_{\text {GS(th) }}$ | Change in $\mathrm{V}_{\text {GS(th) }}$ with temperature | - | -4.3 | -5.5 | $\mathrm{mV} /{ }^{\circ} \mathrm{C}$ | $V_{G S}=V_{D S}, I_{D}=-10 \mathrm{~mA}$ |
| $\mathrm{I}_{\text {GSs }}$ | Gate body leakage | - | -1.0 | -100 | nA | $V_{G S}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0 \mathrm{~V}$ |
| $\mathrm{I}_{\text {Dss }}$ | Zero gate voltage drain current | - | - | -50 | $\mu \mathrm{A}$ | $\mathrm{V}_{\text {GS }}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=$ Max Rating |
|  |  | - | - | -10 | mA | $\begin{aligned} & V_{D S}=0.8 \mathrm{Max} \text { Rating, } \\ & V_{G S}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=125^{\circ} \mathrm{C} \end{aligned}$ |
| $I_{\text {D(ON) }}$ | On-state drain current | -0.85 | -2.0 | - |  | $\mathrm{V}_{G S}=-5.0 \mathrm{~V}, \mathrm{~V}_{\text {DS }}=-25 \mathrm{~V}$ |
|  |  | -4.0 | -9.0 | - | A | $V_{G S}=-10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=-25 \mathrm{~V}$ |
| $\mathrm{R}_{\text {DS(ON) }}$ | Static drain-to-source on-state resistance | - | 1.3 | 1.5 | $\Omega$ | $\mathrm{V}_{\text {GS }}=-5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-1.0 \mathrm{~A}$ |
|  |  | - | 0.75 | 0.9 |  | $V_{G S}=-10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-3.5 \mathrm{~A}$ |
| $\Delta \mathrm{R}_{\text {DS(ON) }}$ | Change in $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ with temperature | - | 0.85 | 1.2 | \%/ ${ }^{\circ} \mathrm{C}$ | $V_{G S}=-10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-3.5 \mathrm{~A}$ |
| $\mathrm{G}_{\text {FS }}$ | Forward transductance | 800 | 1400 | - | mmho | $V_{D S}=-25 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-2.0 \mathrm{~A}$ |
| $\mathrm{C}_{\text {ISS }}$ | Input capacitance | - | 325 | 450 | pF | $\begin{aligned} & V_{G S}=0 \mathrm{~V}, \\ & V_{\text {DS }}=-25 \mathrm{~V}, \\ & f=1.0 \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\text {oss }}$ | Common source output capacitance | - | 125 | 180 |  |  |
| $\mathrm{C}_{\text {RSS }}$ | Reverse transfer capacitance | - | 30 | 40 |  |  |
| $\mathrm{t}_{\mathrm{d}(\mathrm{ON})}$ | Turn-on delay time | - | 4.0 | 15 | ns | $\begin{aligned} & V_{D D}=-25 \mathrm{~V}, \\ & I_{D}^{=}=-4.0 \mathrm{~A}, \\ & R_{G E N}=10 \Omega \end{aligned}$ |
| $\mathrm{t}_{\mathrm{r}}$ | Rise time | - | 16 | 25 |  |  |
| $\mathrm{t}_{\text {d(IFF) }}$ | Turn-off delay time | - | 16 | 50 |  |  |
| $\mathrm{t}_{\mathrm{f}}$ | Fall time | - | 22 | 50 |  |  |
| $\mathrm{V}_{\text {SD }}$ | Diode forward voltage drop | - | -1.1 | -1.6 | V | $\mathrm{V}_{\text {GS }}=0 \mathrm{~V}, \mathrm{I}_{\text {SD }}=-3.5 \mathrm{~A}$ |
| $\mathrm{t}_{\text {tr }}$ | Reverse recovery time | - | 500 | - | ns | $\mathrm{V}_{\text {GS }}=0 \mathrm{~V}, \mathrm{I}_{\text {SD }}=-1.0 \mathrm{~A}$ |

## Notes:

1. All D.C. parameters $100 \%$ tested at $25^{\circ} \mathrm{C}$ unless otherwise stated. (Pulse test: $300 \mu$ s pulse, $2 \%$ duty cycle.)
2. All A.C. parameters sample tested.

## Switching Waveforms and Test Circuit



## Typical Performance Curves






## Typical Performance Curves (cont.)






## 3-Lead TO-39 Package Outline (N2)



Bottom View


Side View

| Symbol |  | $\alpha$ | $\beta$ | A | ¢а | ¢b | ¢D | ¢D1 | h | j | k | L |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dimension (inches) | MIN | $\begin{gathered} 45^{\circ} \\ \text { NOM } \end{gathered}$ | $\begin{gathered} 90^{\circ} \\ \text { NOM } \end{gathered}$ | . 240 | . 190 | . 016 | . 350 | . 315 | . 009 | . 028 | . 029 | . 500 |
|  | NOM |  |  | - | - | - | - | - | - | - | - | - |
|  | MAX |  |  | . 260 | . 210 | . 021 | . 370 | . 335 | . 125 | . 034 | . 040 | .560* |

JEDEC Registration TO-39.

* This dimension is not specified in the JEDEC drawing.


## Drawings not to scale.

Supertex Doc. \#: DSPD-3TO39N2, Version B052009

## 3-Lead TO-92 Package Outline (N3)



Front View


Side View


Bottom View

| Symbol |  | A | b | c | D | E | E1 | e | e1 | L |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dimensions (inches) | MIN | . 170 | . $014{ }^{+}$ | . $014{ }^{+}$ | . 175 | . 125 | . 080 | . 095 | . 045 | . 500 |
|  | NOM | - | - | - | - | - | - | - | - | - |
|  | MAX | . 210 | . $022^{+}$ | .022 ${ }^{+}$ | . 205 | . 165 | . 105 | . 105 | . 055 | .610* |

JEDEC Registration TO-92.

* This dimension is not specified in the JEDEC drawing
$\dagger$ This dimension differs from the JEDEC drawing.
Drawings not to scale.
Supertex Doc.\#: DSPD-3TO92N3, Version E041009.
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

[^1]
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[^0]:    Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

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